

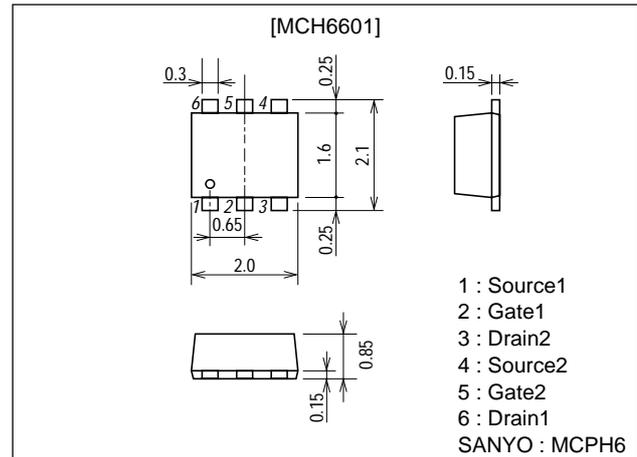
**MCH6601****Ultrahigh-Speed Switching Applications****Features**

- Low ON resistance.
- Ultrahigh-speed switching.
- 2.5V drive.
- Composite type with 2 MOSFETs contained in one package, facilitating high-density mounting.

**Package Dimensions**

unit:mm

2173

**Specifications****Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	$V_{DSS}$		-30	V
Gate-to-Source Voltage	$V_{GSS}$		±10	V
Drain Current (DC)	$I_D$		-0.2	A
Drain Current (pulse)	$I_{DP}$	PW≤10μs, duty cycle≤1%	-0.8	A
Allowable Power Dissipation	$P_D$	Mounted on a ceramic board (900mm <sup>2</sup> ×0.8mm) 1unit	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

**Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=-1mA, V_{GS}=0$	-30			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-30V, V_{GS}=0$			-10	μA
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 8V, V_{DS}=0$			±10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=-10V, I_D=-100\mu A$	-0.4		-1.4	V
Forward Transfer Admittance	yfs	$V_{DS}=-10V, I_D=-50mA$	80	110		mS
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=-50mA, V_{GS}=-4V$		8	10.4	Ω
	$R_{DS(on)2}$	$I_D=-30mA, V_{GS}=-2.5V$		11	15.4	Ω
	$R_{DS(on)3}$	$I_D=-1mA, V_{GS}=-1.5V$		27	54	Ω

Marking : FA

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**SANYO Electric Co.,Ltd. Semiconductor Company**

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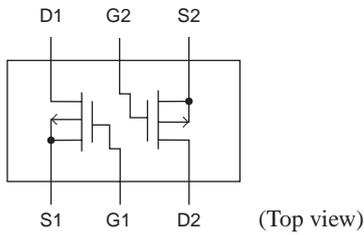
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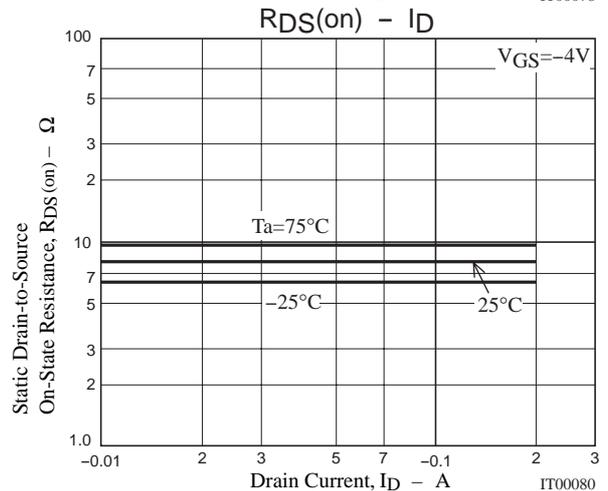
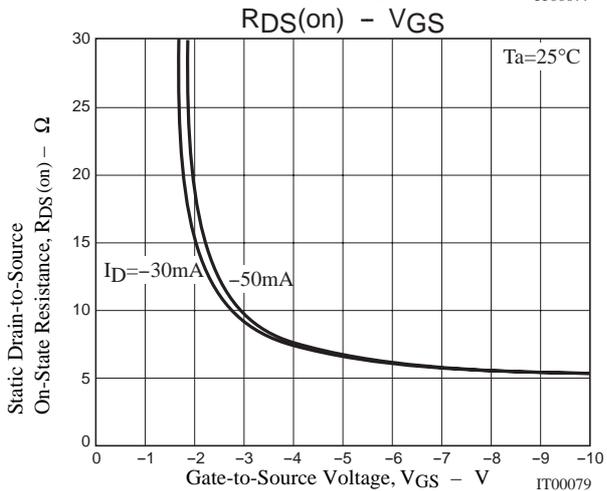
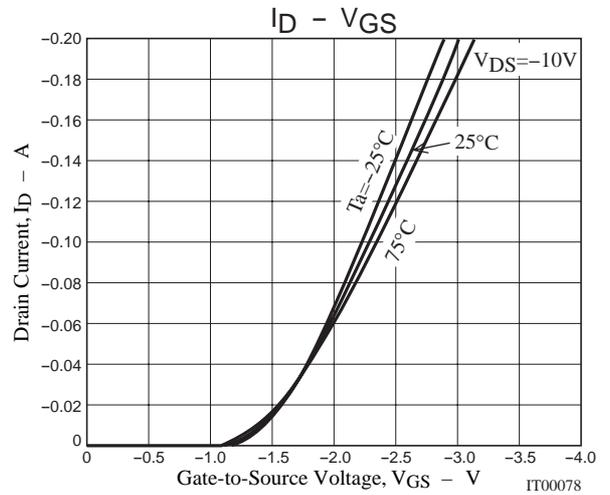
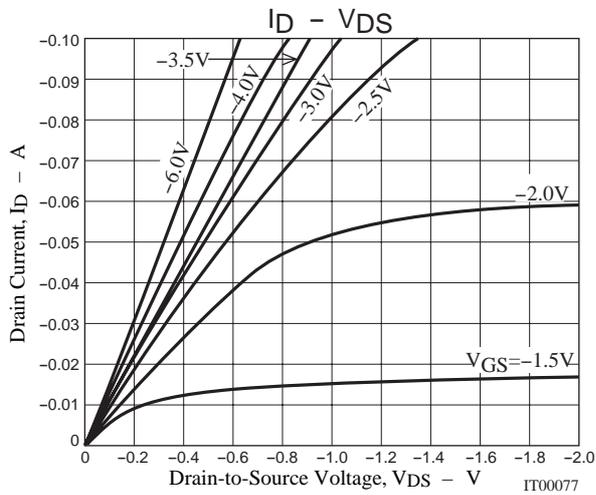
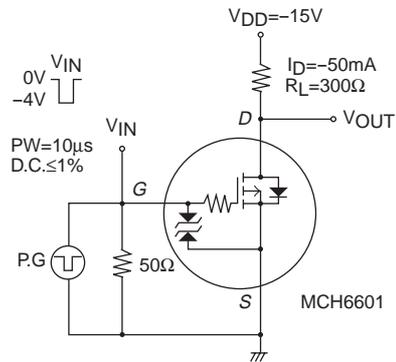
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	$C_{iss}$	$V_{DS}=-10V, f=1MHz$		7.5		pF
Output Capacitance	$C_{oss}$	$V_{DS}=-10V, f=1MHz$		5.7		pF
Reverse Transfer Capacitance	$C_{rss}$	$V_{DS}=-10V, f=1MHz$		1.8		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		24		ns
Rise Time	$t_r$	See specified Test Circuit		55		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		120		ns
Fall Time	$t_f$	See specified Test Circuit		130		ns
Total Gate Charge	$Q_g$	$V_{DS}=-10V, V_{GS}=-10V, I_D=-100mA$		1.43		nC
Gate-to-Source Charge	$Q_{gs}$	$V_{DS}=-10V, V_{GS}=-10V, I_D=-100mA$		0.18		nC
Gate-to-Drain "Miller" Charge	$Q_{gd}$	$V_{DS}=-10V, V_{GS}=-10V, I_D=-100mA$		0.25		nC
Diode Forward Voltage	$V_{SD}$	$I_S=-100mA, V_{GS}=0$		0.83	1.2	V

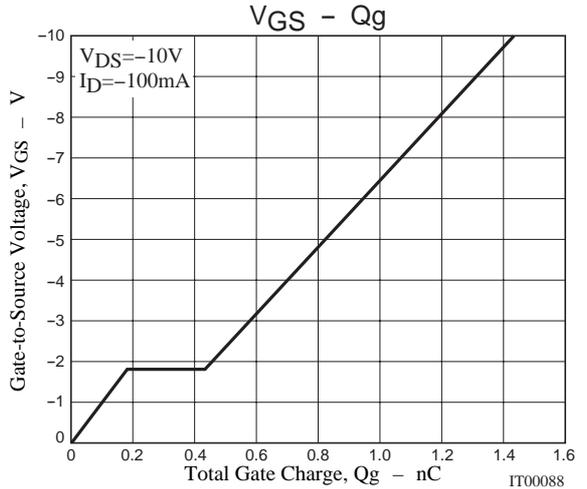
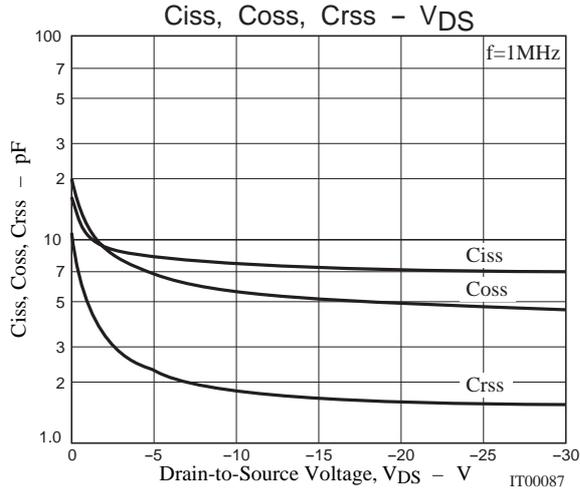
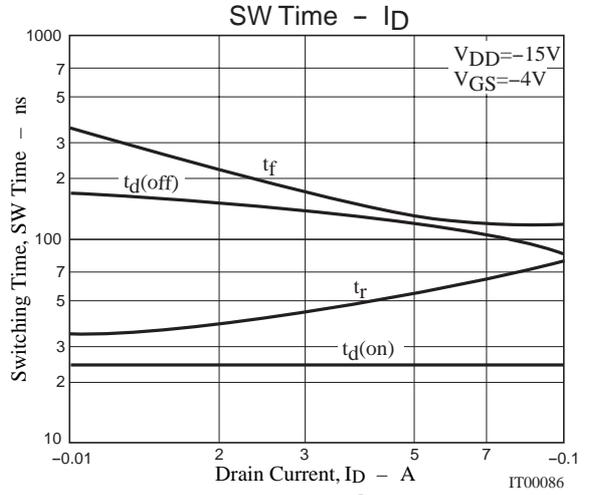
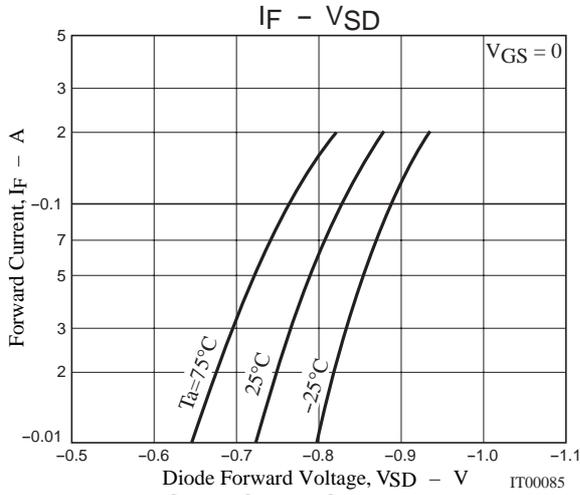
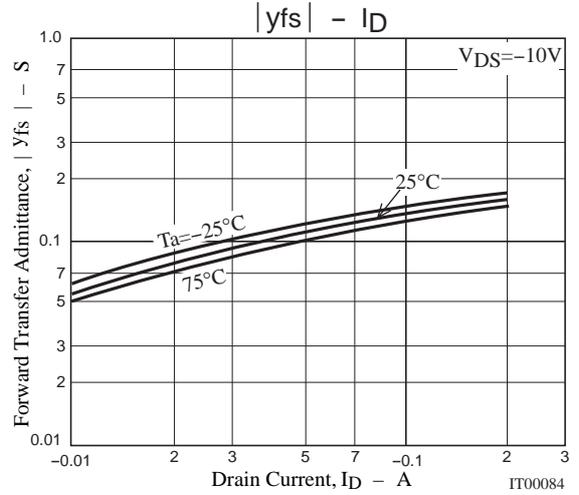
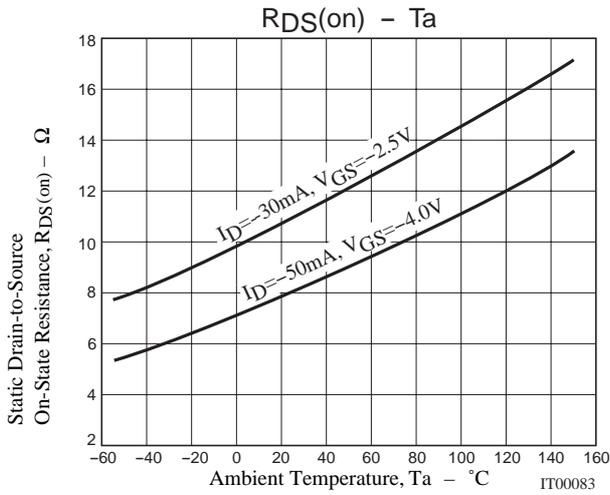
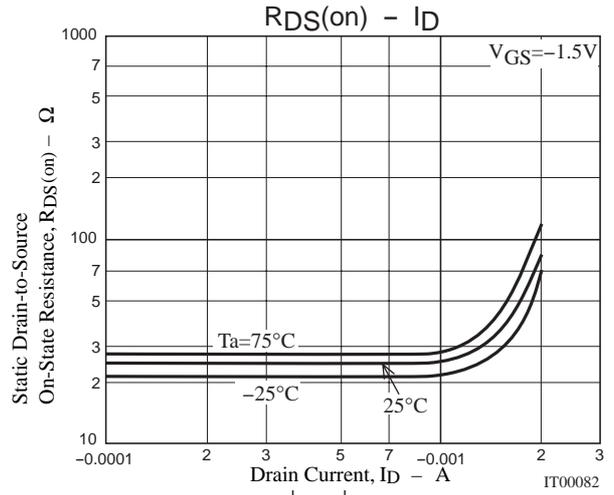
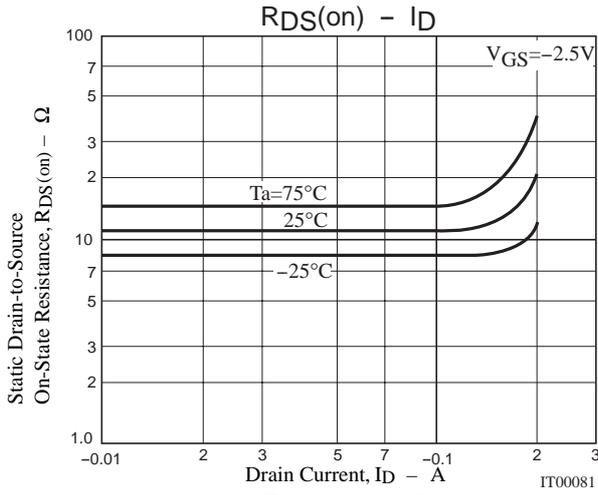
## Electrical Connection



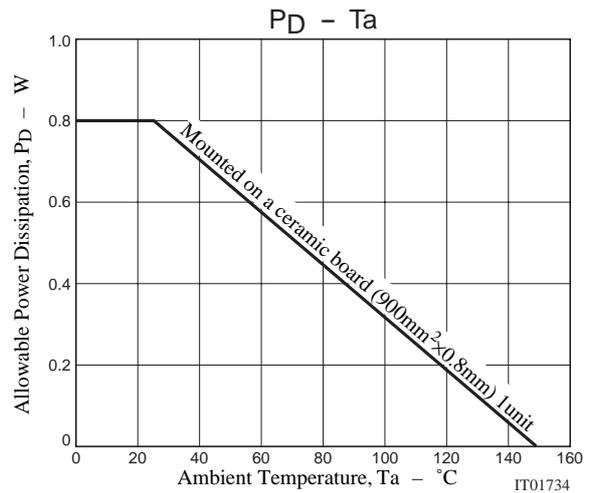
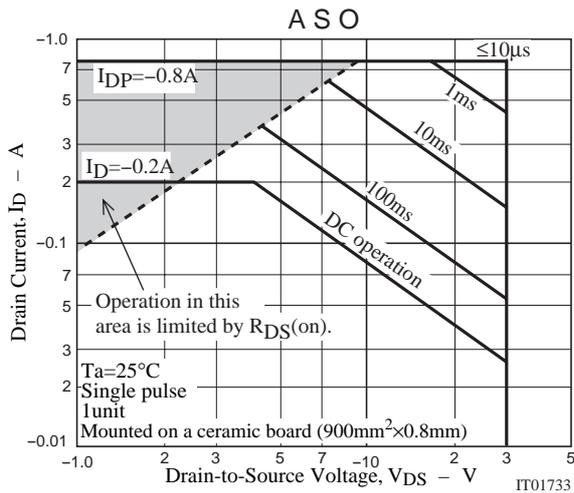
## Switching Time Test Circuit



# MCH6601



# MCH6601



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